

CMOS Digital Integrated Circuits Silicon Monolithic

74HCT540D,74HCT541D

1. Functional Description

· Octal Bus Buffer

74HCT540D: INVERTING, 3-STATE OUTPUTS 74HCT541D: NON-INVERTING, 3-STATE OUTPUTS

2. General

The 74HCT540D/74HCT541D are high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C2MOS technology.

These devices may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

They achive the high speed operation similar to equivalent LSTTL while maintaing the CMOS low power dissipation.

The 74HCT540D is an inverting type, and the 74HCT541D is a non-inverting type.

When either $\overline{G}1$ or $\overline{G}2$ are high, the terminal outputs are in the high-impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features

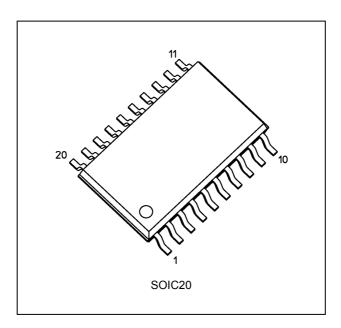
- (1) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 1)
- (2) High speed: $t_{pd} = 9 \text{ ns (typ.)}$ at $V_{CC} = 5.5 \text{ V}$
- (3) Low power dissipation: $I_{CC} = 4.0 \mu A \text{ (max)}$ at $T_a = 25 \text{ °C}$
- (4) Compatible with TTL outputs: $V_{IL} = 0.8 \text{ V(max)}$

 $V_{IH} = 2.0 \text{ V(min)}$

- (5) Wide interfacing ability: LSTTL, NMOS, CMOS
- (6) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$

Note 1: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

4. Packaging



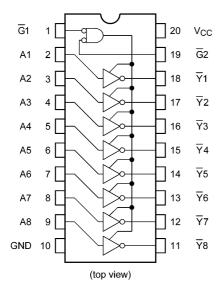
Start of commercial production

2020-07

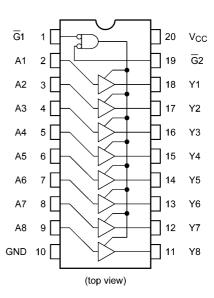


5. Pin Assignment

74HCT540D

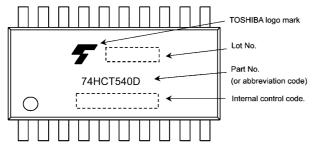


74HCT541D

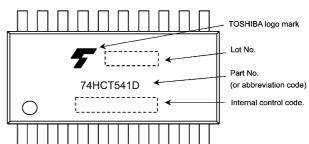


6. Marking



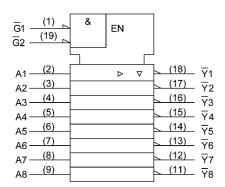


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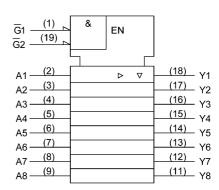


7. IEC Logic Symbol

74HCT540D



74HCT541D





8. Truth Table

Input G1	Input G2	Input An	Output Yn	Output \overline{Y} n
Н	Х	Х	Z	Z
Х	Н	X	Z	Z
L	L	Н	Н	L
L	L	L	L	Н

X: Don't care
Z: High impedance
Yn: 74HCT541D
Yn: 74HCT540D

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to V _{CC} + 0.5	٧
Output voltage	V _{OUT}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		±20	mA
Output diode current	I _{OK}		±20	mA
Output current	I _{OUT}		±35	mA
V _{CC} /ground current	I _{CC}		±75	mA
Power dissipation	P _D	(Note 1)	500	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P_D derates linearly with -8 mW/°C above 85 °C

10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		4.5 to 5.5	V
Input voltage	V _{IN}		0 to V _{CC}	V
Output voltage	V _{OUT}		0 to V _{CC}	V
Operating temperature	T _{opr}	(Note 1)	-40 to 125	°C
Input rise and fall times	t _r ,t _f		0 to 500	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	_	_	V
Low-level input voltage	V _{IL}	_		4.5 to 5.5	-	_	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	4.5	4.4	4.5	_	V
			I _{OH} = -6 mA	4.5	4.18	4.31	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	$I_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 20 \mu\text{A}$		_	0.0	0.1	V
			I _{OL} = 6 mA	4.5	_	0.17	0.26	
3-state output OFF-state leakage current	l _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	_	±0.5	μА
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	_	_	±0.1	μА
Quiescent supply	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	μА
current	I _{CCT}	Per input: V _{IN} = 0.5 V or 2.4 V Other input: V _{CC} or GND		5.5	_	_	2.0	mA

11.2. DC Characteristics (Unless otherwise specified, Ta = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	_	V
Low-level input voltage	V _{IL}	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	4.5	4.4	_	V
			$I_{OH} = -6 \text{ mA}$	4.5	4.13	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 20 \mu\text{A}$		_	0.1	V
			I _{OL} = 6 mA	4.5	_	0.33	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$			_	±5.0	μА
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	40.0	μА
	I _{CCT}	Per input: V _{IN} = 0.5 V or 2.4 Other input: V _{CC} or GND	4 V	5.5	_	2.9	mA

11.3. DC Characteristics (Note) (Unless otherwise specified, Ta = -40 to 125 °C)

Characteristics	Symbol	Test Condition	ı	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	_	V
Low-level input voltage	V _{IL}	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	4.5	4.4	_	V
			I _{OH} = -6 mA	4.5	3.7	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 20 \mu\text{A}$		_	0.1	V
			I _{OL} = 6 mA	4.5	_	0.4	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND			_	±5.0	μА
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND	V _{IN} = V _{CC} or GND		_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	80.0	μА
	I _{CCT}	Per input: $V_{IN} = 0.5 \text{ V or } 2.4 \text{ V}$ Other input: V_{CC} or GND		5.5	_	2.9	mA

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



11.4. AC Characteristics (Unless otherwise specified, T_a = 25 °C, Input: t_r = t_f = 6 ns)

Characteristics	Part Number	Symbol	Note	Test Condition	C _L (pF)	V _{CC} (V)	Min	Тур.	Max	Unit
Output transition time		t _{TLH} ,t _{THL}		_	50	4.5	_	7	12	ns
						5.5	_	6	11	
Propagation delay time	74HCT540D	t _{PLH} ,t _{PHL}		_	50	4.5	_	12	20	ns
						5.5		9	18	
					150	4.5	_	17	26	
						5.5	_	14	24	
Propagation delay time	74HCT541D	t _{PLH} ,t _{PHL}		_	50	4.5	_	14	23	ns
						5.5	_	11	21	
					150	4.5	_	19	29	
						5.5	_	16	27	
3-state output enable time		t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	50	4.5	_	18	30	ns
						5.5	_	16	27	
					150	4.5	_	23	36	
						5.5	_	21	33	
3-state output disable time		t_{PLZ},t_{PHZ}		$R_L = 1 k\Omega$	50	4.5	_	18	30	ns
						5.5	_	16	27	
Input capacitance		C _{IN}		_			_	5	10	pF
Output capacitance		C _{OUT}		_				10	_	pF
Power dissipation	74HCT540D	C _{PD}	(Note 1)	_			_	35	_	pF
capacitance	74HCT541D	C _{PD}		_			_	31	_	

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{|N} + I_{CC}/8 \text{ (per bit)}$

11.5. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_r = t_f = 6 ns)

Characteristics	Part Number	Symbol	Test Condition	C _L (pF)	V _{CC} (V)	Min	Max	Unit
Output transition time		t _{TLH} ,t _{THL}	_	50	4.5	_	15	ns
					5.5	_	14	
Propagation delay time	74HCT540D	t _{PLH} ,t _{PHL}	_	50	4.5	_	25	ns
					5.5	_	23	
				150	4.5	_	33	
					5.5	_	30	
Propagation delay time	74HCT541D	t _{PLH} ,t _{PHL}	_	50	4.5		29	ns
					5.5	_	27	
				150	4.5	_	36	
					5.5	_	33	
3-state output enable time		t _{PZL} ,t _{PZH}	$R_L = 1 k\Omega$	50	4.5	_	38	ns
					5.5	_	35	
				150	4.5	_	45	
					5.5	_	41	
3-state output disable time		t_{PLZ}, t_{PHZ}	$R_L = 1 k\Omega$	50	4.5	_	38	ns
					5.5	_	35	
Input capacitance		C _{IN}		_		_	10	pF



11.6. AC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 6 ns)

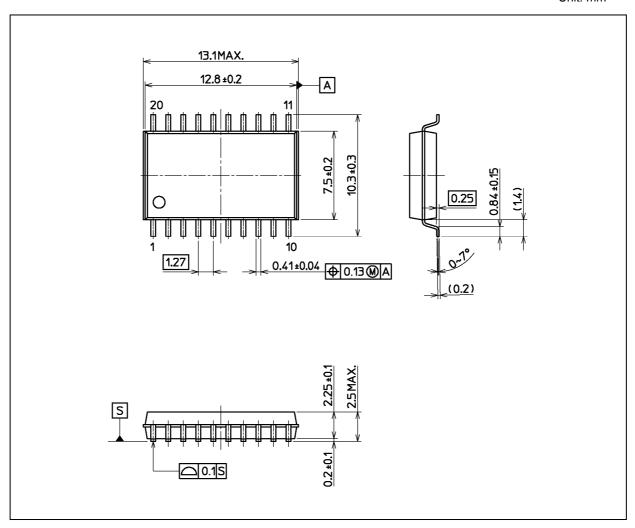
Characteristics	Part Number	Symbol	Test Condition	C _L (pF)	V _{CC} (V)	Min	Max	Unit
Output transition time		t _{TLH} ,t _{THL}	_	50	4.5	_	17	ns
					5.5	_	16	
Propagation delay time	74HCT540D	t _{PLH} ,t _{PHL}	_	50	4.5		29	ns
					5.5	_	27	
				150	4.5	_	38	
					5.5	_	34	
Propagation delay time	74HCT541D	t _{PLH} ,t _{PHL}	_	50	4.5	_	33	ns
					5.5	_	31	
				150	4.5	_	41	
					5.5	_	37	
3-state output enable time		t_{PZL}, t_{PZH}	$R_L = 1 k\Omega$	50	4.5	_	44	ns
					5.5	_	41	
				150	4.5	_	51	
					5.5	_	47	
3-state output disable time		t_{PLZ}, t_{PHZ}	$R_L = 1 k\Omega$	50	4.5	_	44	ns
					5.5	_	41	
Input capacitance		C _{IN}					10	pF

Note: Operating Range spec of T_{opr} = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



Package Dimensions

Unit: mm



Weight: 0.51 g (typ.)

	Package Name(s)
Nickname: SOIC20	



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